NSN 5961-01-061-9859

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View Online at https://aerobasegroup.com/nsn/5961-01-061-9859

Inclosure Material:

Metal

Overall Length:

0.085 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.230 inches

Function For Which Designed:

Switching

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-46

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Pnp

Mounting Method:

Terminal

Terminal Circle Diameter:

Between 0.090 inches and 0.110 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-30.0 collector to base voltage/static/emitter open and -20.0 collector to emitter voltage/static/base open and -30.0 emitter to base voltage,

static, collector open and -20.0 emitter to collector voltage, dc

Current Rating Per Characteristic:

100.00 milliamperes source cutoff current

Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Test Data Document:

88818-a532a063 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

